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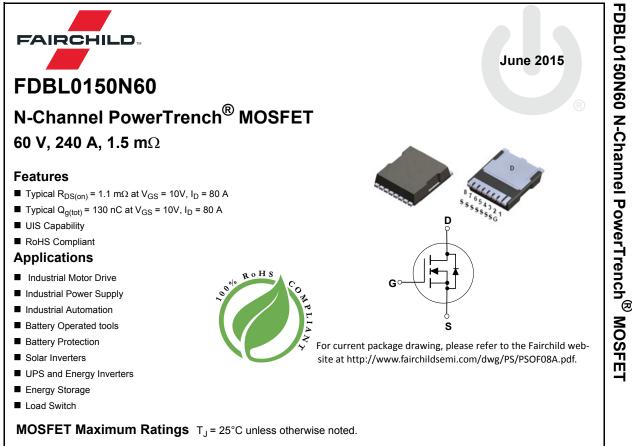


# **ON Semiconductor**®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="mailto:www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to <a href="mailto:Fairchild\_questions@onsemi.com">Fairchild\_questions@onsemi.com</a>.

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Symbol	Parameter		Ratings	Units	
V <sub>DSS</sub>	Drain-to-Source Voltage		60	V	
V <sub>GS</sub>	Gate-to-Source Voltage		±20	V	
I <sub>D</sub>	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	T <sub>C</sub> =25°C	240	•	
	Pulsed Drain Current	T <sub>C</sub> = 25°C	See Figure 4	— A	
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	614	mJ	
<b>D</b>	Power Dissipation		357	W	
P <sub>D</sub>	Derate Above 25°C		2.38	W/ <sup>o</sup> C	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 175	°C	
R <sub>0JC</sub>	Thermal Resistance, Junction to Case		0.42	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

Notes:

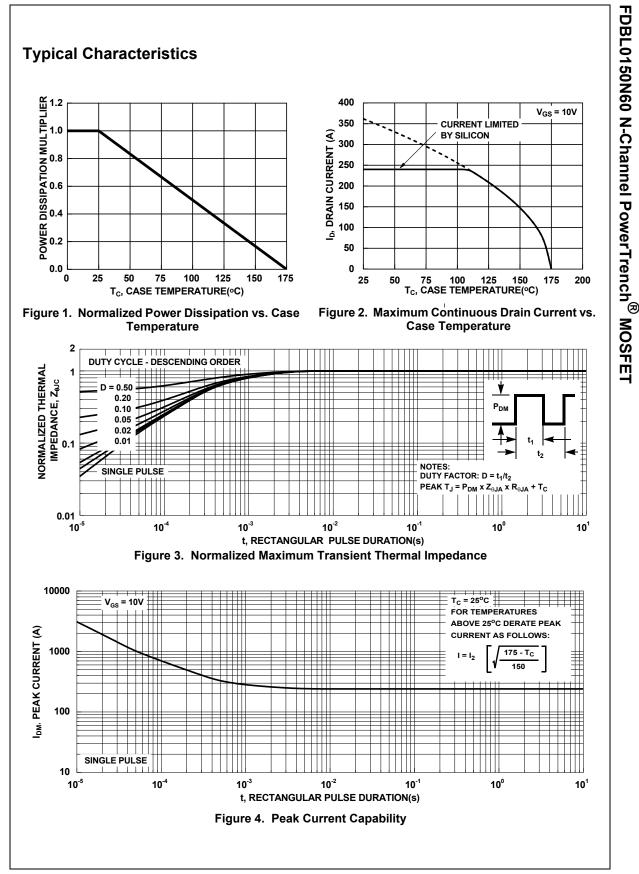
- 1: Current is limited by silicon. 2: Starting  $T_J = 25^{\circ}C$ , L = 0.3mH,  $I_{AS} = 64A$ ,  $V_{DD} = 60V$  during inductor charging and  $V_{DD} = 0V$  during time in avalanche. 3:  $R_{0JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder The maximum rating is a sufficient of the drain pine.  $P_{AB}$  is a quaranteed by design, while  $P_{AB}$  is the termined by the board design. The maximum rating  $_{0,JA}^{0,JA}$  is guaranteed by design, while  $R_{0,JA}$  is guaranteed by design, while  $R_{0,JA}$  is determined by the board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

## **Package Marking and Ordering Information**

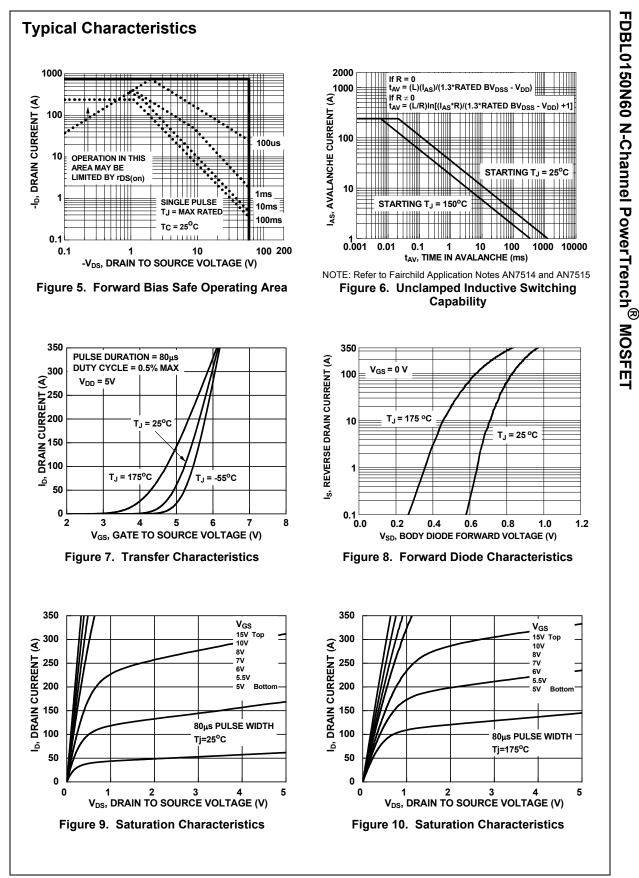
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDBL0150N60	FDBL0150N60	MO-299A	13"	24mm	2000 units

Symbol	Parameter	Test Conditions			Min.	Тур.	Max.	Units
Off Cha	racteristics							
B <sub>VDSS</sub>	Drain-to-Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V			60	-	-	V
	Drain to Source Lookage Current	V <sub>DS</sub> =60V,	T <sub>J</sub> = 2	5°C	-	-	1	μA
I <sub>DSS</sub>	Drain-to-Source Leakage Current	$V_{GS} = 0V$	$T_{J} = 1$	75 <sup>o</sup> C (Note 4)	-	-	1	mA
I <sub>GSS</sub>	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA	
On Cha	racteristics							
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 250μA			2.0	2.9	4.0	V
		I <sub>D</sub> = 80A,			-	1.1	1.5	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 10V	$T_{\rm GS} = 10V$ $T_{\rm J} = 175^{\circ}C$ (Note 4		-	2.1	2.9	mΩ
Dynami	ic Characteristics							
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, f = 1MHz		-	10300	-	pF	
C <sub>oss</sub>	Output Capacitance			-	2590	-	pF	
C <sub>rss</sub>	Reverse Transfer Capacitance			-	270	-	pF	
Rg	Gate Resistance	f = 1MHz		-	4.3	-	Ω	
Q <sub>g(ToT)</sub>	Total Gate Charge at 10V	$V_{GS} = 0$ to 10	VC	V <sub>DD</sub> = 48V	-	130	169	nC
Q <sub>g(th)</sub>	Threshold Gate Charge	V <sub>GS</sub> = 0 to 2V		I <sub>D</sub> = 80A	-	19	-	nC
Q <sub>gs</sub>	Gate-to-Source Gate Charge			- -	-	48	-	nC
Q <sub>gd</sub>	Gate-to-Drain "Miller" Charge				-	20	-	nC
Switchi	ng Characteristics							
t <sub>on</sub>	Turn-On Time				-	-	160	ns
t <sub>d(on)</sub>	Turn-On Delay			-	-	30	-	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 30V, I	<sub>D</sub> = 80.	А,	-	77	-	ns
t <sub>d(off)</sub>	Turn-Off Delay	$V_{GS} = 10V, R_{GEN} = 6\Omega$		-	78	-	ns	
t <sub>f</sub>	Fall Time			-	57	-	ns	
t <sub>off</sub>	Turn-Off Time			-	-	-	200	ns
Drain-S	ource Diode Characteristics	I		I				
V <sub>SD</sub>	Source-to-Drain Diode Voltage	I <sub>SD</sub> =80A, V <sub>GS</sub> = 0V		-	-	1.25	V	
		I <sub>SD</sub> = 40A, V <sub>GS</sub> = 0V		-	-	1.2	V	
t <sub>rr</sub>	Reverse-Recovery Time	$I_F = 80A, dI_{SD}/dt = 100A/\mu s,$ $V_{DD}=48V$		-	94	140	ns	
Q <sub>rr</sub>	Reverse-Recovery Charge			-	131	200	nC	

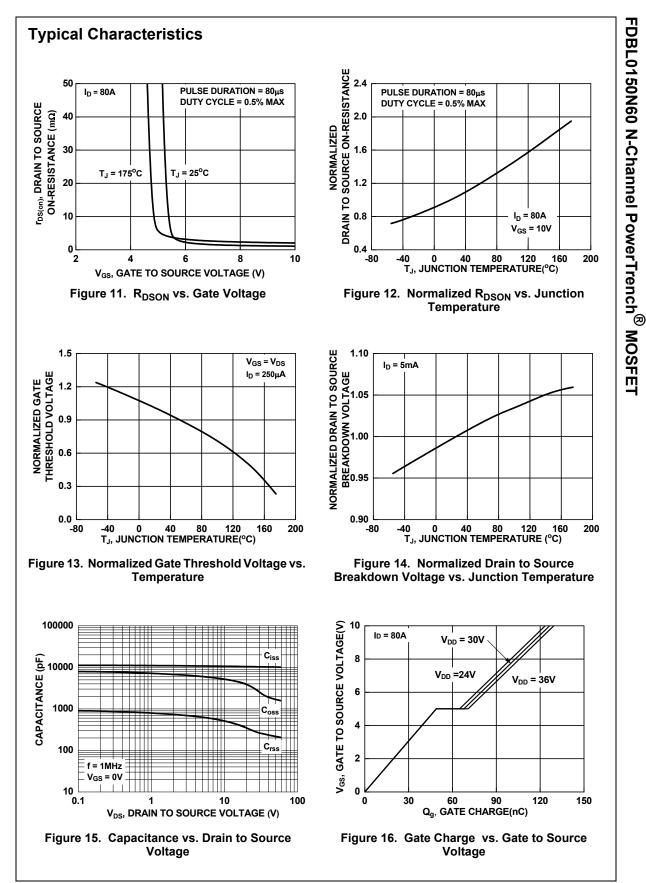
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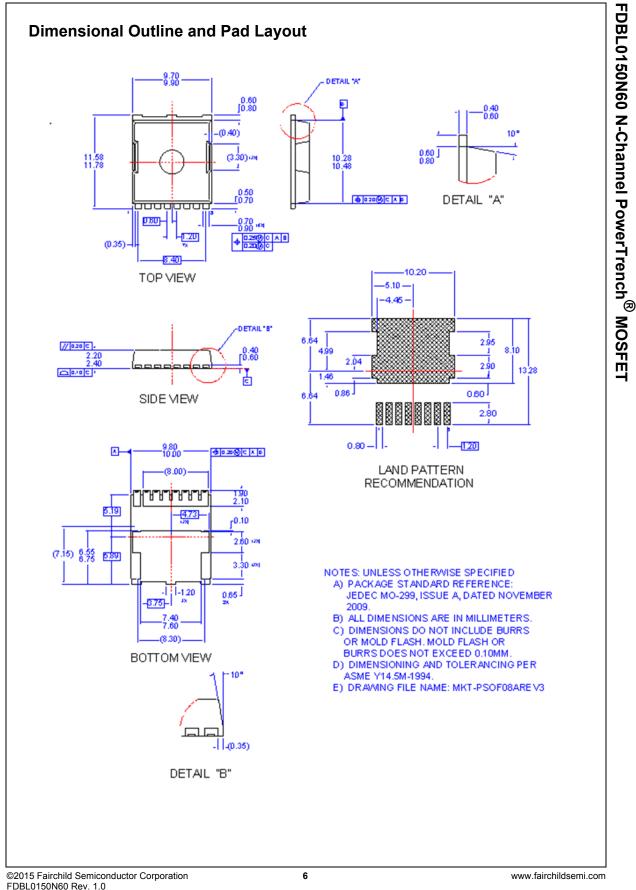
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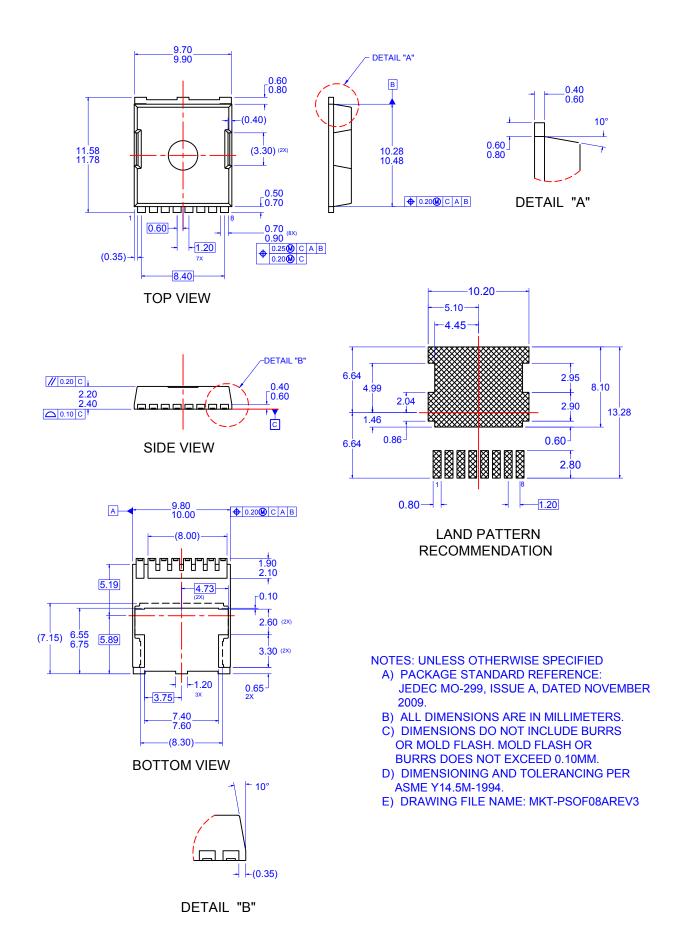


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